# VS-150EBU04

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**Vishay Semiconductors** 

# Ultrafast Soft Recovery Diode, 150 A FRED Pt<sup>®</sup>



**PowerTab**<sup>®</sup>

### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	150 A			
V <sub>R</sub>	400 V			
V <sub>F</sub> at I <sub>F</sub>	0.9 V			
t <sub>rr</sub> (typ.)	See recovery table			
T <sub>J</sub> max.	175 °C			
Package	PowerTab <sup>®</sup>			
Circuit configuration	Single			

### **FEATURES**

- · Ultrafast recovery time
- 175 °C max. operating junction temperature
- · Screw mounting only
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47



RoHS

COMPLIANT · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

### **DESCRIPTION / APPLICATIONS**

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

### **MECHANICAL DATA**

Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating Terminal: nickel plated, screwable

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V <sub>R</sub>		400	V
Continuous forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 104 °C	150	
Single pulse forward current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	1500	А
Maximum repetitive forward current	I <sub>FRM</sub>	Square wave, 20 kHz	300	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT S
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 200 μA	400	-	-	
Forward voltage		I <sub>F</sub> = 150 A	-	1.07	1.3	v
	V <sub>F</sub>	I <sub>F</sub> = 150 A, T <sub>J</sub> = 175 °C	-	0.9	1.1	
		I <sub>F</sub> = 150 A, T <sub>J</sub> = 125 °C	-	0.96	1.17	
Reverse leakage current	1	$V_R = V_R$ rated	-	-	50	μA
	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	4	mA
Junction capacitance	CT	V <sub>R</sub> = 400 V	-	100	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	3.5	-	nH

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, \text{ d}_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$	a = 200 A/μs, V <sub>R</sub> = 30 V	-	-	60	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	93	-	ns
	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 150 A V <sub>R</sub> = 200 V dI⊧/dt = 200 A/µs	-	172	-		
Peak recovery current I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	11	-	A	
	T <sub>J</sub> = 125 °C		-	20	-		
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	490	-	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1740	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.22	0.29	K/W
Thermal resistance, junction to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.2	-	rv vv
Weight			-	-	5.02	g
Weight			-	0.18	-	oz.
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style PowerTab <sup>®</sup>		150E	BU04	·

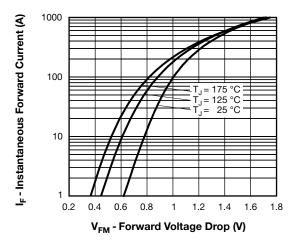


Fig. 1 - Maximum Forward Voltage Drop Characteristics

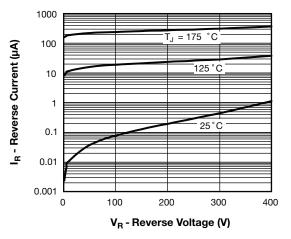
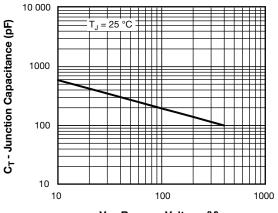


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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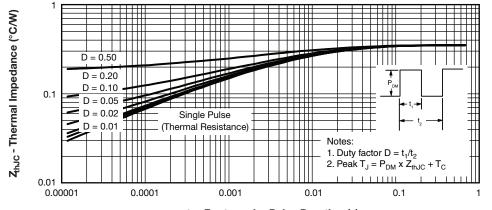
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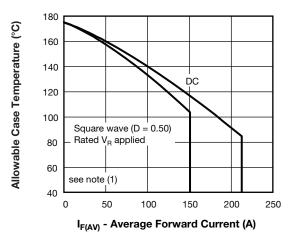
V<sub>R</sub> - Reverse Voltage (V)

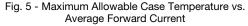
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



t<sub>1</sub> - Rectangular Pulse Duration (s)

Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics





#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

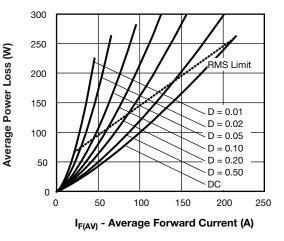


Fig. 6 - Forward Power Loss Characteristics

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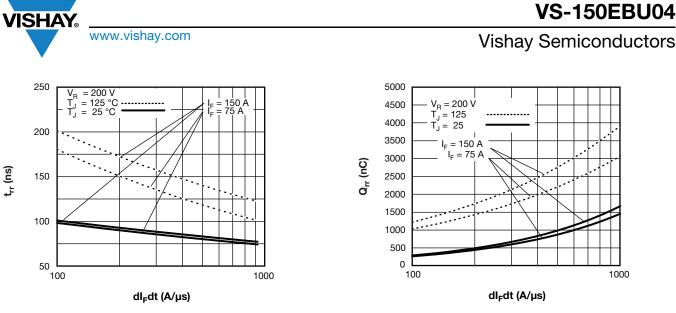


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

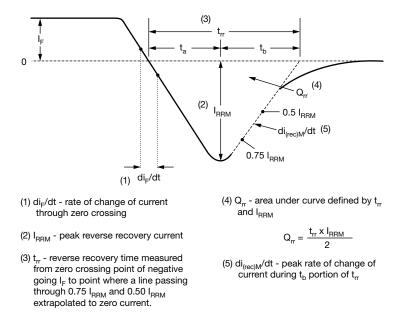
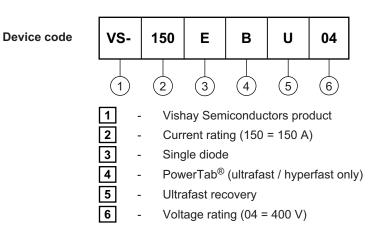


Fig. 9 - Reverse Recovery Waveform and Definitions



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### **ORDERING INFORMATION TABLE**



ORDERING INFORMATI	ON		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-150EBU04	25	375	Antistatic plastic tube

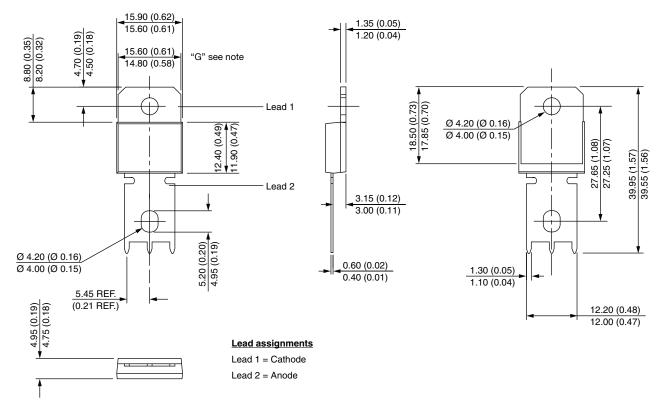
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95240				
Part marking information	www.vishay.com/doc?95370			
Application note	www.vishay.com/doc?95179			



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**PowerTab**<sup>®</sup>

### **DIMENSIONS** in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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